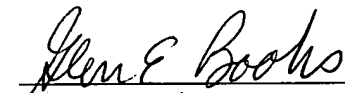


**REMARKS**

The Advisory Action mailed December 13, 2002 objected to proposed claim 1 submitted June 25, 2002 on the ground that the self-assembled monolayer is formed on the substrate, not on the stamp. This is correct. A proposed amended claim 1 is submitted herewith to clarify any ambiguity on the point. This claim is supported by the specification at p. 6, lines 3 - 7 which points out that the self-assembled monolayer is on the substrate.

It is submitted that entry of this amendment would remove the Section 112 rejection of this case and place it in condition for allowance. Entry and favorable action in this regard is therefore earnestly solicited.

Respectfully submitted,

  
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Glen E. Books  
Reg. No. 24,950  
Attorney for Applicants

Date: February 13, 2003

LOWENSTEIN SANDLER PC  
65 Livingston Avenue  
Roseland, New Jersey 07068  
973-597-6162



**VERSION SHOWING CHANGES MADE**

Claim 1:

1. A method for making an organic transistor on a substrate comprising the steps of:

providing a substrate including a metal surface layer;

providing a rotatable stamp having relief geometries on its surface to define a stamping surface;

applying a [self-assembled monolayer] SAMS ink to the surface of the rotatable stamp to define an inked stamping surface;

rotating the rotatable stamp on the metal surface layer as the layer is placed in contact with the stamp to form on the layer [an inked] a self-assembled monolayer pattern as defined by the inked stamping surface; and

patterning the layer by etching material from the layer wherein the inked stamping surface guides the etching in a geometry to define the patterned layer useful in fabricating an electronic device;

removing the inked pattern from the layer; and

applying an organic semiconductor layer overlying the etched metal layer.